Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	3209	hafnium adj oxide	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/30 06:16
S2	4009	ald or atomic adj layer adj deposition	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/23 09:10
S3	0	hafnium adj oxide1 and (ald or atomic adj layer adj deposition)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/30 06:16
S4	264	(hafnium adj oxide) and (ald or atomic adj layer adj deposition)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/30 06:16
S5	589910	capacitor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/30 06:17
S6	120	((hafnium adj oxide) and (ald or atomic adj layer adj deposition)) and capacitor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/30 06:42
S7	45	ruthenium and ((hafnium adj oxide) and (ald or atomic adj layer adj deposition))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/30 06:42
S8	6536	ald or atomic adj layer adj deposition	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/23 09:10
S9	8045	purge and graph	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/23 09:10

S10	281	S8 and S9	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/23 09:10
S11	12482	capacitor adj dielectric	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/23 09:10
S12	46	S10 and S11	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/23 09:10